SEMICONDUCTOR

74LCX32245 Low Voltage 32-Bit Bidirectional Transceiver with 5V Tolerant Inputs and Outputs

General Description

The LCX32245 contains thirty-two non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 32-bit operation. The T/\overline{R} inputs determine the direction of data flow through the device. The \overline{OE} inputs disable both the A and B ports by placing them in a high impedance state.

The LCX32245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

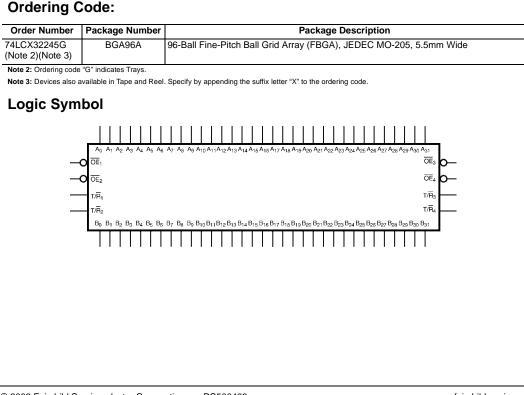
- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 4.5 ns t_{PD} max (V_{CC} = 3.3V), 20 µA I_{CC} max
- Power down high impedance inputs and outputs

November 2001

Revised June 2002

- Supports live insertion/withdrawal (Note 1)
- \pm 24 mA output drive (V_{CC} = 3.0V)
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human body model > 2000V Machine model > 200V
- Packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.



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74LCX32245

Connection	Diagram
	123456
A	000000
Δ	000000
C	000000
D	000000
ш	000000
ш	000000
ហ	000000
т	000000
ر	000000
¥	000000
L	000000
Σ	000000
z	000000
<u>م</u>	000000
ш	000000
F	000000

(Top Thru View)

Pin Descriptions

Pin Names	Description
OEn	Output Enable Input (Active LOW)
T/R _n	Transmit/Receive Input
A ₀ -A ₃₁	Side A Inputs or 3-STATE Outputs
B ₀ -B ₃₁	Side B Inputs or 3-STATE Outputs

FBGA Pin Assignments

	1	2	3	4	5	6
Α	B ₁	B ₀	T/R ₁	OE ₁	A ₀	A ₁
В	B ₃	B ₂	GND	GND	A ₂	A ₃
С	В ₅	B ₄	V _{CC}	V _{CC}	A ₄	Α ₅
D	В ₇	B ₆	GND	GND	A ₆	A ₇
Е	B ₉	B ₈	GND	GND	A ₈	A ₉
F	B ₁₁	B ₁₀	V _{CC}	V _{CC}	A ₁₀	A ₁₁
G	B ₁₃	B ₁₂	GND	GND	A ₁₂	A ₁₃
н	B ₁₄	B ₁₅	T/\overline{R}_2	OE ₂	A ₁₅	A ₁₄
J	B ₁₇	B ₁₆	T/R_3	OE ₃	A ₁₆	A ₁₇
Κ	B ₁₉	B ₁₈	GND	GND	A ₁₈	A ₁₉
L	B ₂₁	B ₂₀	V _{CC}	V _{CC}	A ₂₀	A ₂₁
М	B ₂₃	B ₂₂	GND	GND	A ₂₂	A ₂₃
Ν	B ₂₅	B ₂₄	GND	GND	A ₂₄	A ₂₅
Р	B ₂₇	B ₂₆	V _{CC}	V _{CC}	A ₂₆	A ₂₇
R	B ₂₉	B ₂₈	GND	GND	A ₂₈	A ₂₉
т	B ₃₀	В ₃₁	T/R ₄	\overline{OE}_4	A ₃₁	A ₃₀

Truth Tables

	Inputs	Outputs
OE ₁	T/R ₁	Outputs
L	L	Bus B ₀ –B ₇ Data to Bus A ₀ –A ₇
L	н	Bus $A_0 - A_7$ Data to Bus $B_0 - B_7$
Н	Х	HIGH Z State on A ₀ -A ₇ , B ₀ -B ₇

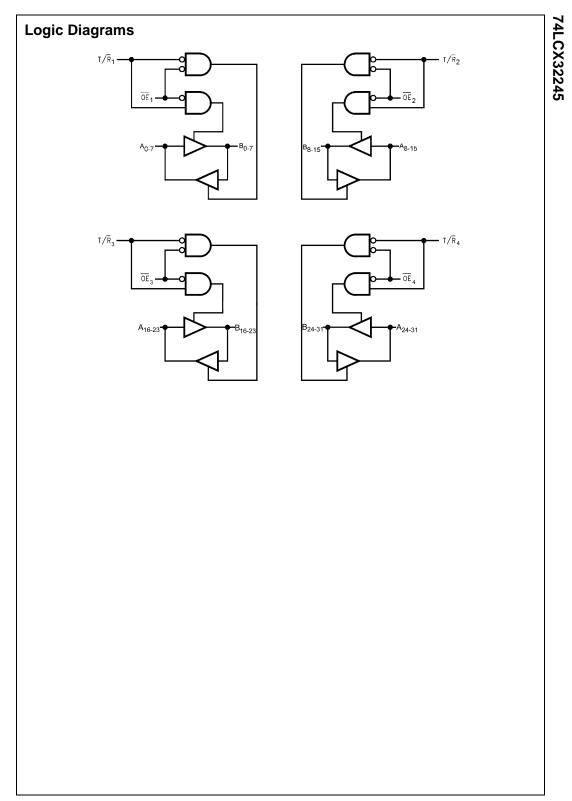
In	puts	Outpute
OE ₂	T/R ₂	Outputs
L	L	Bus B ₈ –B ₁₅ Data to Bus A ₈ –A ₁₅
L	Н	Bus B_8-B_{15} Data to Bus A_8-A_{15} Bus A_8-A_{15} Data to Bus B_8-B_{15}
Н	Х	HIGH Z State on A ₈ -A ₁₅ , B ₈ -B ₁₅

Inp	uts	Outrasta
OE ₃	T/R_3	- Outputs
L	L	Bus B ₁₆ –B ₂₃ Data to Bus A ₁₆ –A ₂₃
L	Н	Bus A ₁₆ –A ₂₃ Data to Bus B ₁₆ –B ₂₃
Н	Х	HIGH Z State on A_{16} - A_{23} , B_{16} - B_{23}

ſ	Inp	uts	• • • •
	OE ₄	T/R ₄	Outputs
	L	L	Bus B ₂₄ –B ₃₁ Data to Bus A ₂₄ –A ₃₁
	L	Н	Bus A_{24} - A_{31} Data to Bus B_{24} - B_{31}
	Н	Х	HIGH Z State on A ₂₄ -A ₃₁ , B ₂₄ -B ₃₁

X = Immaterial (HIGH or LOW, inputs and I/O's may not float) Z = High Impedance

H = HIGH Voltage Level L = LOW Voltage Level



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Absolute Maximum Ratings(Note 4)

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Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		-0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 5)	v
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
Ι _{ΟΚ}	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	IIIA
lo	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current per Supply Pin	±100		mA
I _{GND}	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions (Note 6)

Symbol	Parameter		Min	Max	Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	v
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	
		$V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	mA
		$V_{CC}=2.3V-2.7V$		±8	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_{O} Absolute Maximum Rating must be observed.

Note 6: Unused inputs or I/O's must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Cumhal	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units
Symbol	Parameter	Conditions	(V)	Min	Max	Units
/ _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
/ _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		I _{OH} = -8 mA	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
/ _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		$I_{OL} = 8mA$	2.3		0.6	
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
1	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μΑ
oz	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	
		$V_I = V_{IH} \text{ or } V_{IL}$				μA
OFF	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0		10	μA

DC Electrical Characteristics (Continued)

Symbol	bol Parameter Conditions		V _{CC}	$T_A = -40^{\circ}$	C to +85°C	Units	
Symbol Parameter		Conditions	(V)	Min	Max	onits	
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3–3.6		20	μA	
		$3.6V \le V_I, V_O \le 5.5V$ (Note 7)	2.3–3.6		±20	μΑ	
ΔI _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3-3.6		500	μA	

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

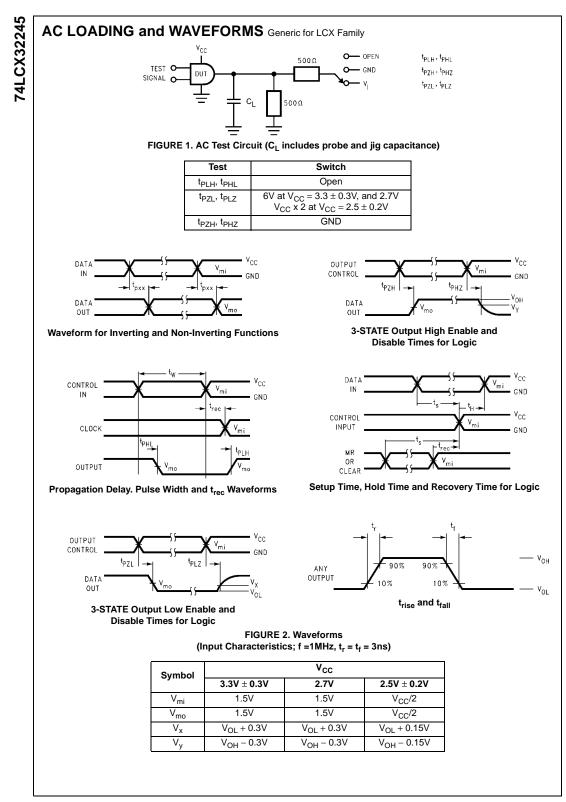
Symbol	Parameter	$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $R_L = 500\Omega$						
		$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units
		t _{PHL}	Propagation Delay	1.5	4.5	1.5	5.2	1.5
t _{PLH}	A _n to B _n or B _n to A _n	1.5	4.5	1.5	5.2	1.5	5.4	
t _{PZL}	Output Enable Time	1.5	6.5	1.5	7.2	1.5	8.5	ns
t _{PZH}		1.5	6.5	1.5	7.2	1.5	8.5	
t _{PLZ}	Output Disable Time	1.5	6.4	1.5	6.9	1.5	7.7	ns
t _{PHZ}		1.5	6.4	1.5	6.9	1.5	7.7	115

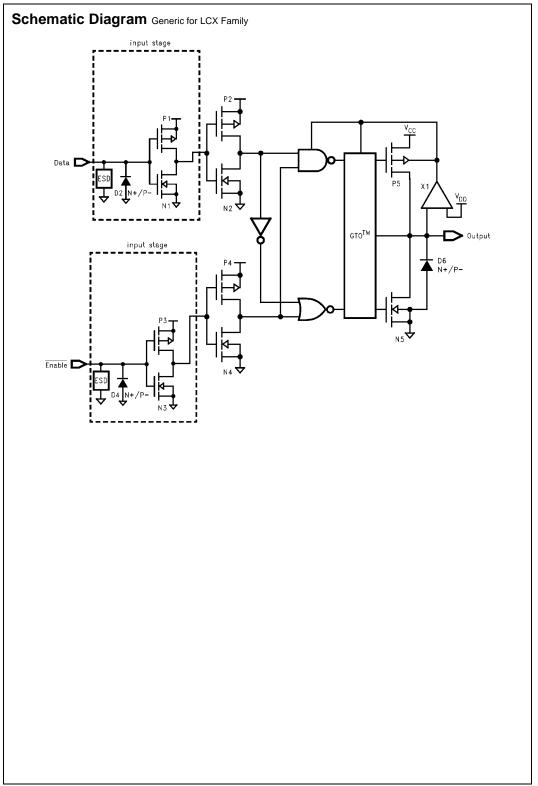
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$\begin{split} & C_L = 50 \text{ pF}, \text{ V}_{IH} = 3.3 \text{V}, \text{ V}_{IL} = 0 \text{V} \\ & C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V} \end{split}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

Capacitance

Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF





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